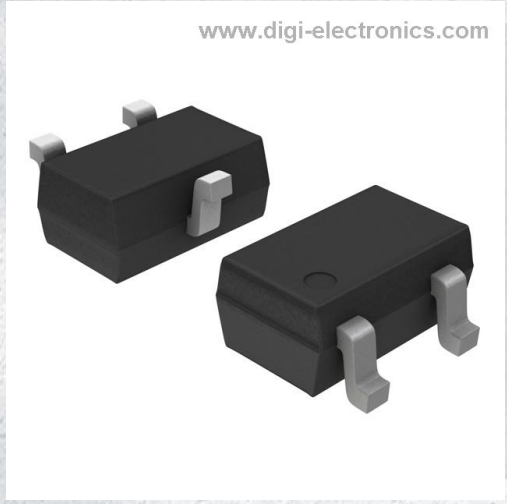
BC857CWT1 Datasheet



https://www.DiGi-Electronics.com

DiGi Electronics Part Number	BC857CWT1-DG
Manufacturer	onsemi
Manufacturer Product Number	BC857CWT1
Description	TRANS PNP 45V 0.1A SC70-3
Detailed Description	Bipolar (BJT) Transistor PNP 45 V 100 mA 100MHz 150 mW Surface Mount SC-70-3 (SOT323)

Tel: +00 852-30501935

RFQ Email: Info@DiGi-Electronics.com

DiGi is a global authorized distributor of electronic components.

Purchase and inquiry

Manufacturer Product Number:	Manufacturer:
BC857CWT1	onsemi
Series:	Product Status:
-	Obsolete
Transistor Type:	Current - Collector (Ic) (Max):
PNP	100 mA
Voltage - Collector Emitter Breakdown (Max):	Vce Saturation (Max) @ Ib, Ic:
45 V	650mV @ 5mA, 100mA
Current - Collector Cutoff (Max):	DC Current Gain (hFE) (Min) @ Ic, Vce:
15nA (ICBO)	420 @ 2mA, 5V
Power - Max:	Frequency - Transition:
150 mW	100MHz
Operating Temperature:	Mounting Type:
-55°C ~ 150°C (TJ)	Surface Mount
Package / Case:	Supplier Device Package:
SC-70, SOT-323	SC-70-3 (SOT323)
Base Product Number:	
BC857	

Environmental & Export classification

RoHS Status:	Moisture Sensitivity Level (MSL):
RoHS non-compliant	1 (Unlimited)
REACH Status:	ECCN:
REACH Unaffected	EAR99
HTSUS:	
8541.21.0075	

BC856BWT1 Series, BC857BWT1 Series, BC858AWT1 Series

Preferred Devices

General Purpose Transistors

PNP Silicon

These transistors are designed for general purpose amplifier applications. They are housed in the SC−70/SOT−323 which is designed for low power surface mount applications.

Features

- Pb−Free Packages are Available

MAXIMUM RATINGS (T_A = 25°C unless otherwise noted)

Rating		Symbol	Value	Unit
Collector-Emitter Voltage	BC856 BC857 BC858	V_{CEO}	−65 −45 −30	V
Collector-Base Voltage	BC856 BC857 BC858	V_{CBO}	−80 −50 −30	V
Emitter−Base Voltage		V_{EBO}	−5.0	V
Collector Current − Continuous		I_C	−100	mAdc

THERMAL CHARACTERISTICS

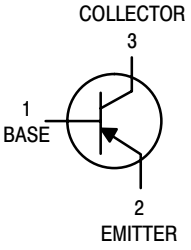
Characteristic	Symbol	Max	Unit
Total Device Dissipation FR−5 Board, (Note 1) T_A = 25°C	P_D	150	mW
Thermal Resistance, Junction−to−Ambient	$R_{\theta JA}$	883	°C/W
Junction and Storage Temperature	T_J, T_{stg}	−55 to +150	°C

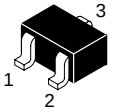
Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

1. FR−5 = 1.0 x 0.75 x 0.062 in.

ON Semiconductor®

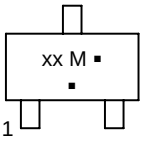
http://onsemi.com





SC−70/SOT−323
CASE 419
STYLE 3

MARKING DIAGRAM



xx = Specific Device Code
M = Date Code*
▪ = Pb−Free Package
(Note: Microdot may be in either location)
*Date Code orientation may vary depending upon manufacturing location.

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 5 of this data sheet.

Preferred devices are recommended choices for future use and best overall value.

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BC856BWT1 Series, BC857BWT1 Series, BC858AWT1 Series

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Characteristic		Symbol	Min	Typ	Max	Unit
OFF CHARACTERISTICS						
Collector−Emitter Breakdown Voltage (I_C = −10 mA)	BC856 Series BC857 Series BC858 Series	$V_{(BR)CEO}$	−65 −45 −30	− − −	− − −	V
Collector−Emitter Breakdown Voltage (I_C = −10 μA, V_{EB} = 0)	BC856 Series BC857B Only BC858 Series	$V_{(BR)CES}$	−80 −50 −30	− − −	− − −	V
Collector−Base Breakdown Voltage (I_C = −10 μA)	BC856 Series BC857 Series BC858 Series	$V_{(BR)CBO}$	−80 −50 −30	− − −	− − −	V
Emitter−Base Breakdown Voltage (I_E = −1.0 μA)	BC856 Series BC857 Series BC858 Series	$V_{(BR)EBO}$	−5.0 −5.0 −5.0	− − −	− − −	V
Collector Cutoff Current (V_{CB} = −30 V) (V_{CB} = −30 V, T_A = 150°C)		I_{CBO}	− −	− −	−15 −4.0	nA μA
ON CHARACTERISTICS						
DC Current Gain (I_C = −10 μA, V_{CE} = −5.0 V) (I_C = −2.0 mA, V_{CE} = −5.0 V)	BC856A, BC585A BC856B, BC857B, BC858B BC857C BC856A, BC858A BC856B, BC857B, BC858B BC857C	h_{FE}	− − − 125 220 420	90 150 270 180 290 520	− − − 250 475 800	−
Collector−Emitter Saturation Voltage (I_C = −10 mA, I_B = −0.5 mA) (I_C = −100 mA, I_B = −5.0 mA)		$V_{CE(sat)}$	 − −	 − −	 −0.3 −0.65	V
Base−Emitter Saturation Voltage (I_C = −10 mA, I_B = −0.5 mA) (I_C = −100 mA, I_B = −5.0 mA)		$V_{BE(sat)}$	 − −	 −0.7 −0.9	 − −	V
Base−Emitter On Voltage (I_C = −2.0 mA, V_{CE} = −5.0 V) (I_C = −10 mA, V_{CE} = −5.0 V)		$V_{BE(on)}$	 −0.6 −	 − −	 −0.75 −0.82	V
SMALL−SIGNAL CHARACTERISTICS						
Current−Gain − Bandwidth Product (I_C = −10 mA, V_{CE} = −5.0 Vdc, f = 100 MHz)		f_T	100	−	−	MHz
Output Capacitance (V_{CB} = −10 V, f = 1.0 MHz)		C_{ob}	−	−	4.5	pF
Noise Figure (I_C = −0.2 mA, V_{CE} = −5.0 Vdc, R_S = 2.0 kΩ, f = 1.0 kHz, BW = 200 Hz)		NF	−	−	10	dB

BC856BWT1 Series, BC857BWT1 Series, BC858AWT1 Series

BC857/BC858

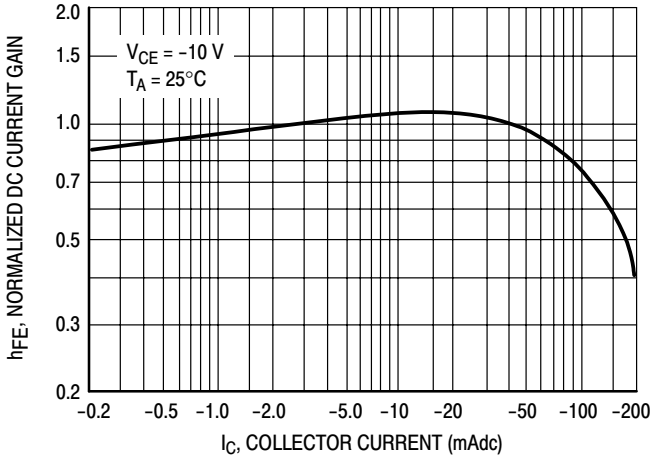


Figure 1. Normalized DC Current Gain

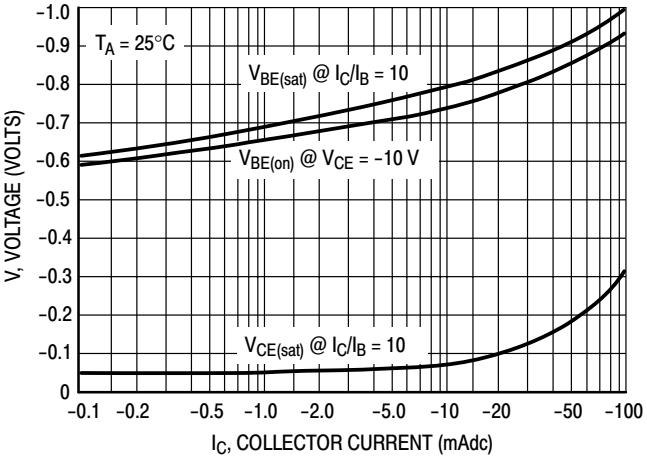


Figure 2. “Saturation” and “On” Voltages

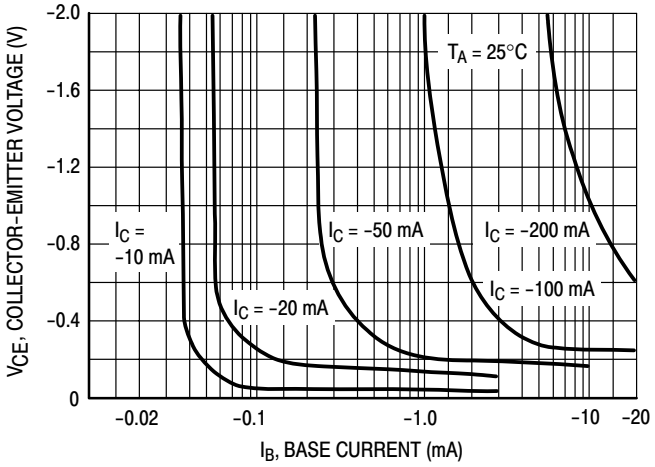


Figure 3. Collector Saturation Region

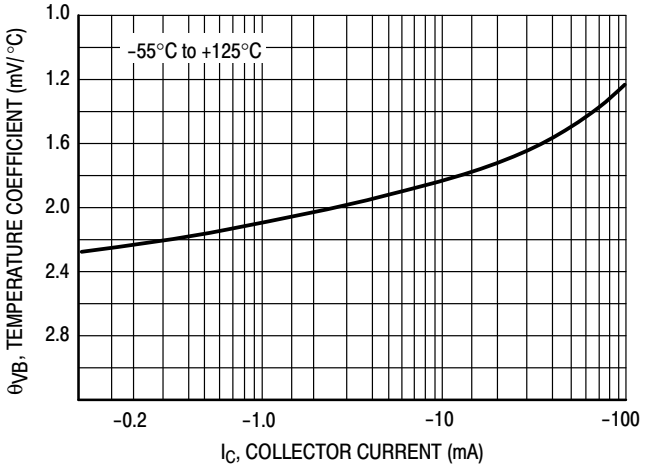


Figure 4. Base−Emitter Temperature Coefficient

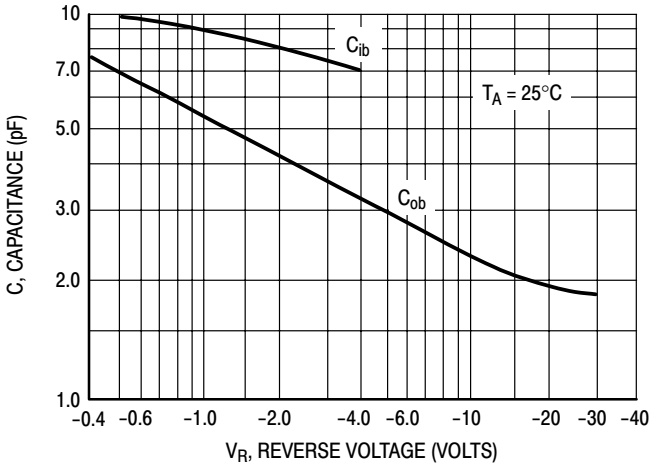


Figure 5. Capacitances

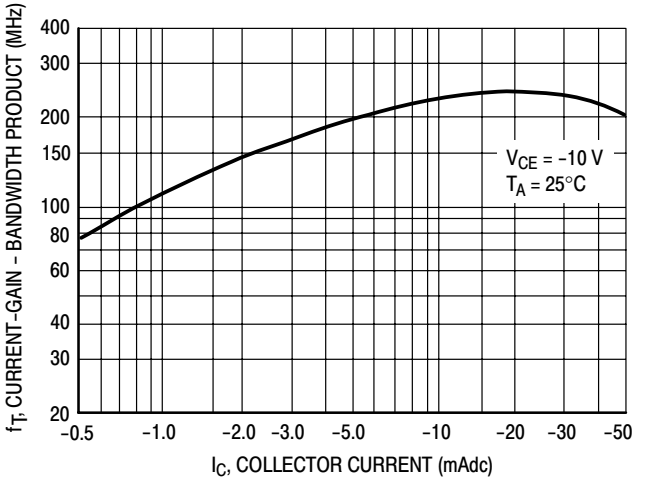


Figure 6. Current−Gain − Bandwidth Product

BC856BWT1 Series, BC857BWT1 Series, BC858AWT1 Series

BC856

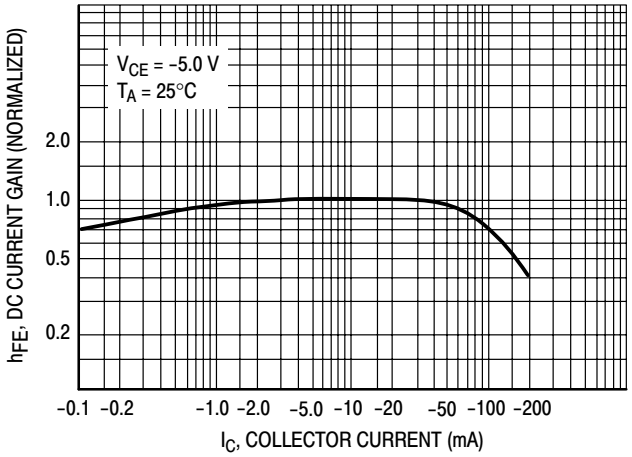


Figure 7. DC Current Gain

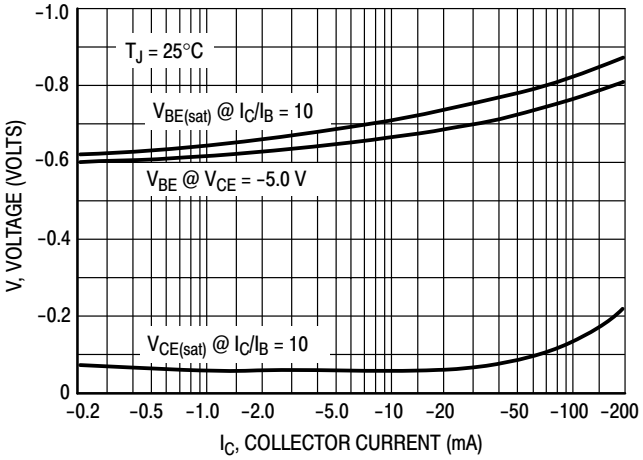


Figure 8. “On” Voltage

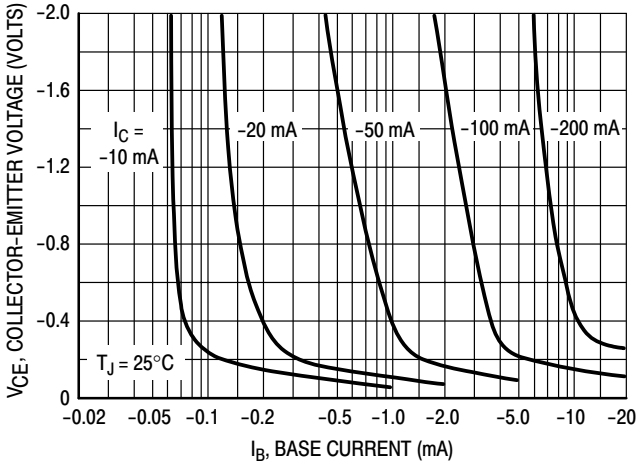


Figure 9. Collector Saturation Region

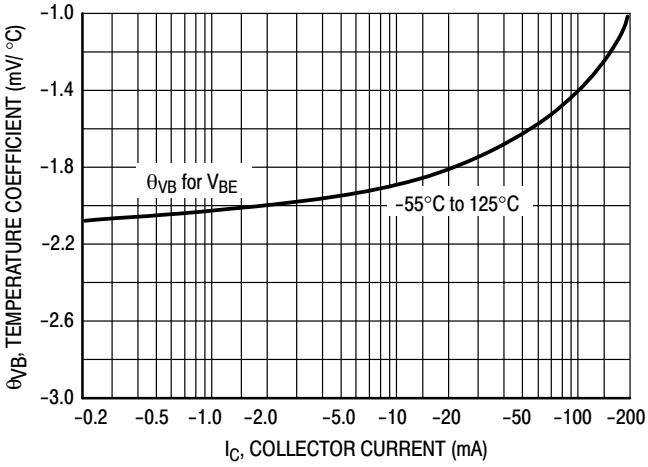


Figure 10. Base−Emitter Temperature Coefficient

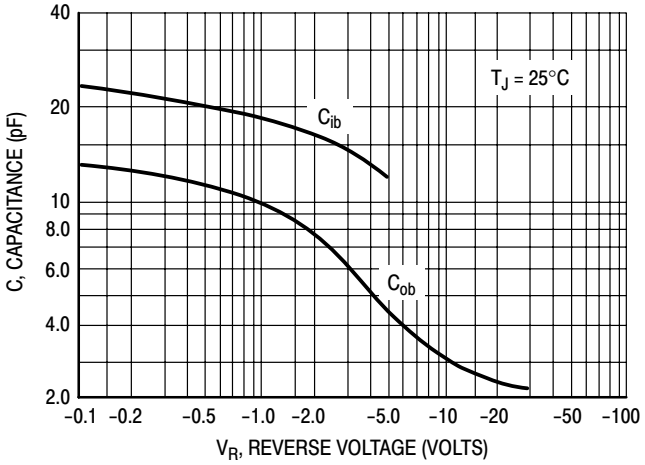


Figure 11. Capacitance

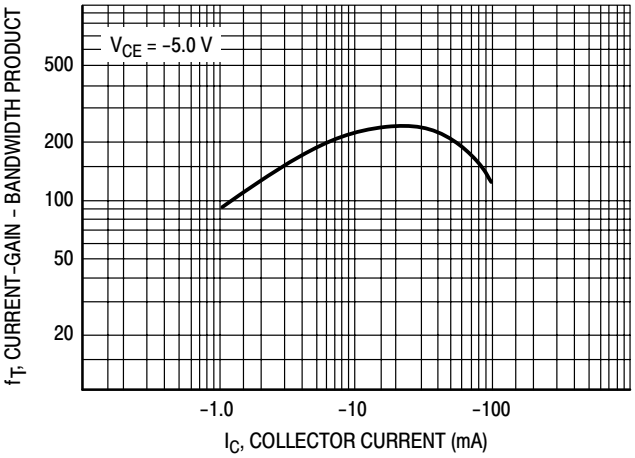


Figure 12. Current−Gain − Bandwidth Product

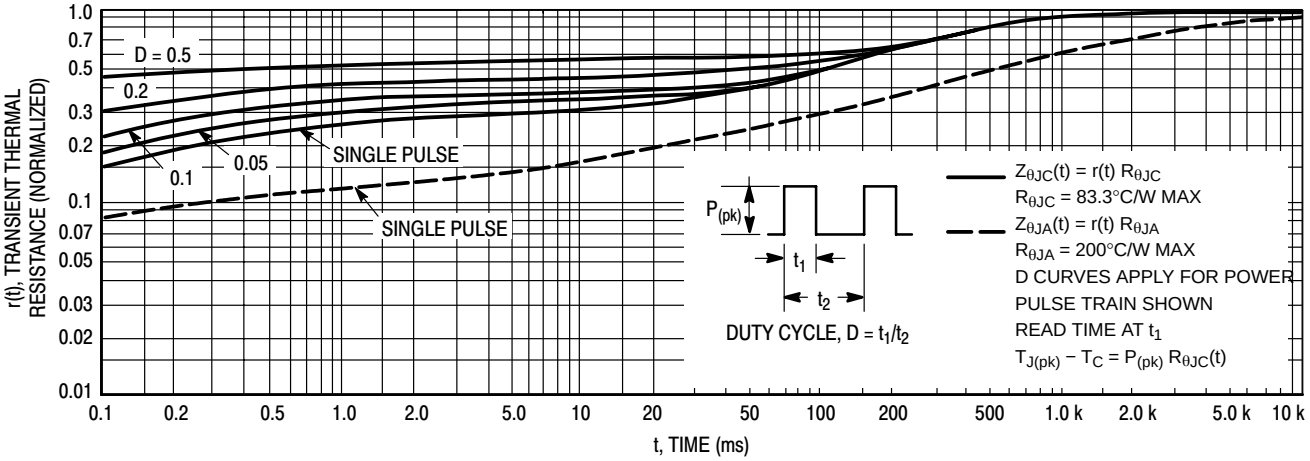


Figure 13. Thermal Response

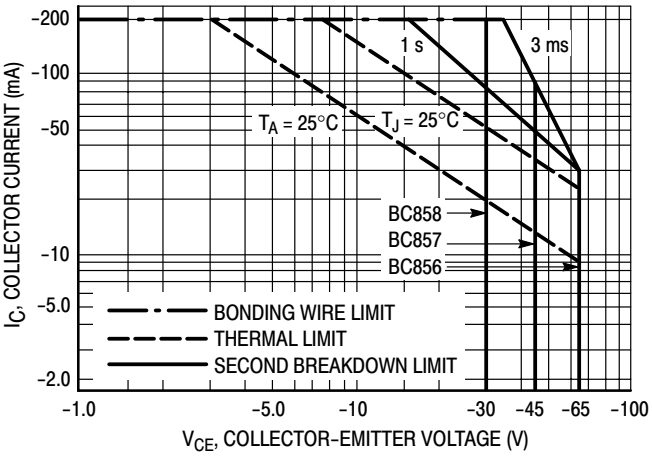


Figure 14. Active Region Safe Operating Area

The safe operating area curves indicate I_C-V_{CE} limits of the transistor that must be observed for reliable operation. Collector load lines for specific circuits must fall below the limits indicated by the applicable curve.

The data of Figure 14 is based upon $T_{J(pk)} = 150°C$; T_C or T_A is variable depending upon conditions. Pulse curves are valid for duty cycles to 10% provided $T_{J(pk)} \le 150°C$. $T_{J(pk)}$ may be calculated from the data in Figure 13. At high case or ambient temperatures, thermal limitations will reduce the power that can be handled to values less than the limitations imposed by the secondary breakdown.

ORDERING INFORMATION

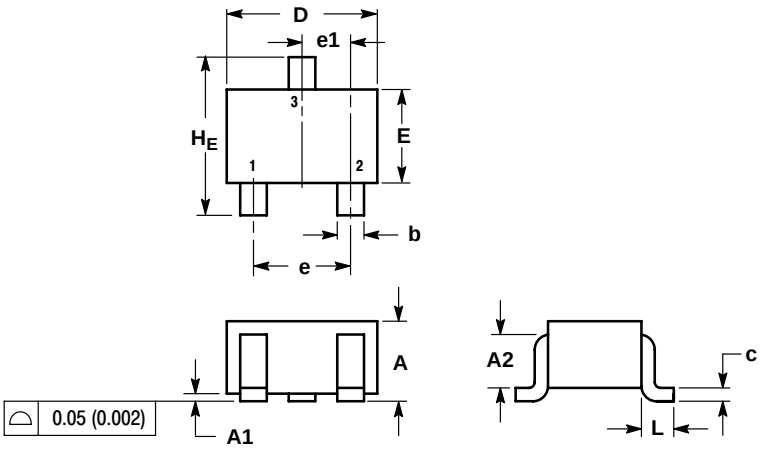
Device	Marking	Package	Shipping†
BC856BWT1	3B	SC−70/SOT−323	3,000 / Tape & Reel
BC856BWT1G		SC−70/SOT−323 (Pb−Free)	
BC857BWT1	3F	SC−70/SOT−323	3,000 / Tape & Reel
BC857BWT1G		SC−70/SOT−323 (Pb−Free)	
BC857CWT1	3G	SC−70/SOT−323	3,000 / Tape & Reel
BC857CWT1G		SC−70/SOT−323 (Pb−Free)	
BC858AWT1	3J	SC−70/SOT−323	3,000 / Tape & Reel
BC858AWT1G		SC−70/SOT−323 (Pb−Free)	
BC858BWT1	3K	SC−70/SOT−323	3,000 / Tape & Reel
BC858BWT1G		SC−70/SOT−323 (Pb−Free)	

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

BC856BWT1 Series, BC857BWT1 Series, BC858AWT1 Series

PACKAGE DIMENSIONS

SC−70 (SOT−323)
CASE 419−04
ISSUE M

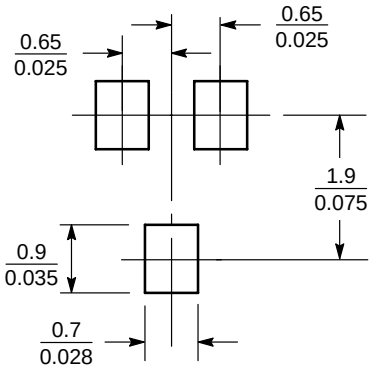


NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.

	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
A	0.80	0.90	1.00	0.032	0.035	0.040
A1	0.00	0.05	0.10	0.000	0.002	0.004
A2		0.7 REF			0.028 REF	
b	0.30	0.35	0.40	0.012	0.014	0.016
c	0.10	0.18	0.25	0.004	0.007	0.010
D	1.80	2.10	2.20	0.071	0.083	0.087
E	1.15	1.24	1.35	0.045	0.049	0.053
e	1.20	1.30	1.40	0.047	0.051	0.055
e1		0.65 BSC			0.026 BSC	
L		0.425 REF			0.017 REF	
H_E	2.00	2.10	2.40	0.079	0.083	0.095

STYLE 3:
PIN 1. BASE
2. EMITTER
3. COLLECTOR

SOLDERING FOOTPRINT*



SCALE 10:1 $\left(\frac{\text{mm}}{\text{inches}}\right)$

*For additional information on our Pb−Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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BC856BWT1/D

OUR CERTIFICATE

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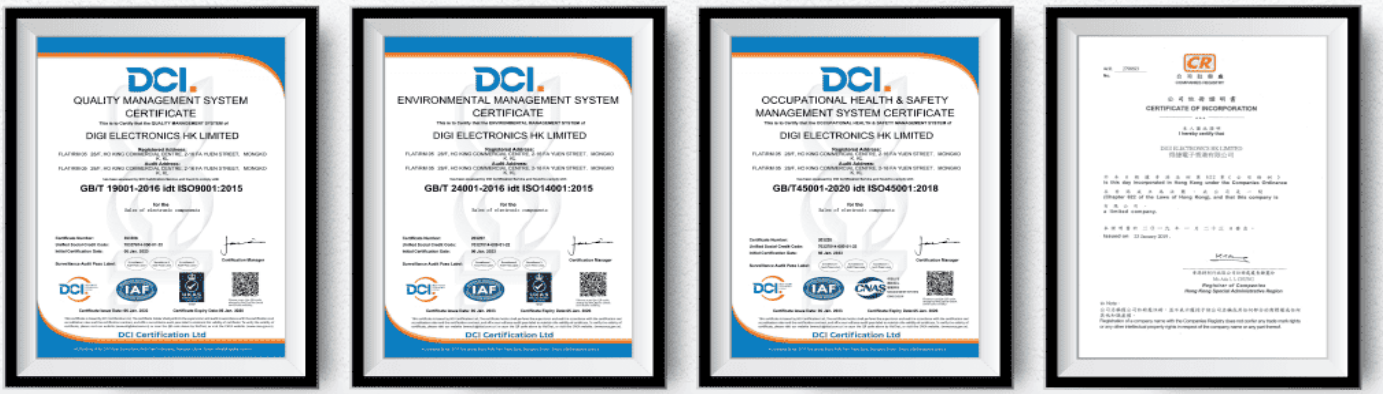

Tel: +00 852-30501935

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